Electronic conductivity in nanostructured TiO$_2$ films permeated with electrolyte

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By combining two experimental techniques, electrochemical impedance spectroscopy (EIS) and the coplanar electrodes–gap configuration, we monitored the electronic conductivity in nanoporous TiO$_2$ in aqueous solution (pH 2) as a function of the electrode potential. As a result of electron accumulation the conductivity varies over more than eight orders of magnitude up to a maximum $\sigma = 3.7 \times 10^{-3} \Omega^{-1} \text{cm}^{-1}$.

Nanoscaled semiconductor materials have become very important for technological developments in photovoltaics, batteries and electrochromic devices. There has been a great deal of recent interest in the electronic conductivity of nanostructured semiconductor materials in different environments [1–4]. In this letter we describe the experimental determination of the electron conductivity in nanocrystalline (nanoporous) TiO$_2$ in aqueous electrolyte, combining different experimental techniques. When the nanoporous TiO$_2$ is biased positively the Fermi level lies very far from the conduction band; hence the carrier concentration is low and the conductivity is very low. Here we use EIS as reported recently [4]. If the electrode potential is displaced in the negative direction, the conductivity increases exponentially. Then it is more convenient to determine the conductivity in situ utilizing a coplanar configuration (similar to source–bridge–drain transistor setup), in which two halves of the film electrode are separated by a non-conducting gap [5, 6]. The two techniques are complementary and enable measurement of the nanoporous film conductivity over a wide range of Fermi level positions with respect to the conduction band potential.

For the measurement of conductivity in the coplanar configuration, TiO$_2$ colloids were prepared by hydrolysis of 1:1 solution of titanium (IV) isopropoxide (Aldrich, 99.9%) and 2-propanol in acetic acid (pH = 2). After overnight aging the organic remainders were evaporated at 82 °C followed by a hydrothermal treatment at 250 °C for 13 hours (titanium autoclave, Parr). The production of the TiO$_2$ slurry was completed by sonication for 5 min, addition of Carbowax (polyethylene glycol compound) to solution and stirring overnight. Using TEM and XRD the TiO$_2$ particles were characterized as 20 nm in diameter anatase crystals. The TiO$_2$ slurry was spread on the interdigitated electrodes (ABTECK), dried in air at room temperature and sintered at 450 °C for 30 min. The thickness of the TiO$_2$ films was $L = 4.5$ μm, measured with Surfest SV 500 profilometer (Mitutoyo Co). The non-conducting gap of the
interdigitated electrode was \( t = 5 \, \mu\text{m} \) wide and \( d = 14.73 \, \text{cm} \) long which provides a high signal to noise ratio. For the EIS sample the process was basically the same with the only difference that the slurry was spread over a normal conducting electrode of area \( A = 3.3 \, \text{cm}^2 \) [4].

We used the EIS technique in a typical three electrode configuration, Fig. 1, with the TiO\(_2\) film as working electrode (WE), a Pt wire as counter electrode (CE) and an Ag/AgCl electrode as reference electrode (RE). Here the potential of the nanoporous electrode is modulated against the reference in a water solution at pH 2 (H\(_2\)SO\(_4\)) [4]. Using an equivalent circuit model stated previously [4], it is possible to calculate the transport resistance, \( R_1 \), corresponding to electron motion along the axis normal to the substrate and the conductivity is determined as \( \sigma = L/R_1A \).

In the coplanar configuration (Fig. 2) the conductivity in pH 2 HClO\(_4\) aqueous solution containing 0.2 M LiClO\(_4\) was measured using a bi-potentiostat. The TiO\(_2\) film sintered on an interdigitated electrode forms two gold supported nanoporous electrodes that are electrically contacted by the TiO\(_2\) layer present in the gap between the two gold contacts. The measurement is based on a simultaneous scan of the two nanoporous WEs between –0.0 V and –0.9 V (vs. Ag/AgCl) while a small constant potential difference between them is maintained. The current flowing across the gap through the TiO\(_2\) is proportional to its conductivity at each potential. We first record the current–voltage dependence of both electrodes without a potential difference across the gap (Fig. 2a, curves 1 and 2). These voltammograms serve as baselines that account for the contact resistance and the electrode charging [7]. Next we measure the current–voltage dependence of both electrodes in the presence of a small potential difference across the gap. For clarity we present in Fig. 2a (curves 3, 4) the forward scan only, showing that the current increases in one of the electrodes while decreasing in the other one. Subtracting the baseline currents (curves 1, 2) from those obtained in the presence of a bias across the gap (curves 3, 4) provides two curves \( i(V) \) of similar shapes but inverse values that correspond to the current flowing across the gap, Fig. 2b (curves 1 and 2). Knowing the cross gap potential, \( \Delta V_{\text{WE1-WE2}} \), one can use Ohm’s law to calculate the resistance across the gap, \( R_g \), as a function of the applied bias voltage, \( V \). Thus the conductivity is calculated as \( \sigma = \iiota R_gLd \). Typically, a 10 mV difference is applied across the gap and the resistance values are confirmed by two additional potential differences to ensure that \( R_g \) corresponds to the linear region of the \( i - \Delta V_{\text{WE1-WE2}} \) dependence. We note that over 95% of the current entering the gap from the more negative electrode arrives at the positive electrode. Consequently electron losses in the gap shown in curve 3 of Fig. 2b may be neglected.
The results of the electron conductivity, $\sigma$, in nanoporous TiO$_2$ electrodes, combining the two measurements are shown in Fig. 3. The match of results of the two techniques is excellent, specially concerning the slope in the region of overlap. This slope is very important, because it indicates the potential-dependence of $\sigma$ (the absolute values may be subjected to a certain error due to indeterminacy in the geometrical factors).

The overall behavior of the conductivity shows two domains separated by the crossover at $-0.5$ V vs. Ag/AgCl. This potential corresponds to the lower edge of the conduction band of anatase TiO$_2$ at pH 2 [7]. Between 0.2 and $-0.5$ V (Ag/AgCl), Fig. 3 shows in a direct fashion the correlation of the electron conductivity to the increasing electron accumulation induced by the potential. Thus variation of $\sigma$ can be understood in terms of the progressive displacement of the Fermi level towards the conduction band, which is related to the photovoltage mechanism in dye sensitized solar cells. In this region the dependence of $\sigma$ on the bias potential is close to exp ($-eV/k_B T$), where $k_B T/e$ is the thermal voltage, i.e. the variation is near to 60 mV/decade. On the other hand, at potentials more negative than $-0.5$ V (Ag/AgCl) a saturation of the conductivity is observed, probably due to a state of Fermi level pinning.

In the case of sintered metal-oxide semiconductor nanoparticles (ca. 10 nm diameter) electrode, mobile ions in solution can screen the electrical fields beyond the nanoscopic dimension, so that the electron transport occurs predominantly by diffusion. Therefore the conductivity in Fig. 3 corresponds to diffusive electron transport and can be written $\sigma = ne\mu$, where $n$ is the carrier density and the mobility relates to the diffusion coefficient as $\mu = eD/k_B T$. The measured value of conductivity in the saturation range is $\sigma = 3.7 \times 10^{-3}$ Ω$^{-1}$ cm$^{-1}$. Assuming $n = 10^{20}$ cm$^{-3}$ in this range (as confirmed by voltammetry [7]) the average electron mobility and diffusion coefficient take the values $\mu = 2.3 \times 10^{-4}$ cm$^2$/Vs and $D = 6.0 \times 10^{-6}$ cm$^2$/s, respectively. These estimated values are similar to those reported by Solbrand et al. [2] in dye-sensitized solar cells ($D = 3–8 \times 10^{-6}$ cm$^2$/s). The explanation of the conductivity features in Fig. 3 in terms of a transport model in which the exponential distribution of traps [7] plays a central role, is currently being developed.

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References